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R. H. H.

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent Application Serial No. 09/920,978
Filing Date August 1, 2001
Inventor Shane J. Trapp
Assignee Micron Technology, Inc.
Group Art Unit 2813
Examiner David S. Blum
Attorney Docket No. MI22-1674
Title: Method of Forming Integrated Circuitry and Method of Forming Shallow
Trench Isolation in a Semiconductor Substrate

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

References -- See Attached Form PTO-1449

The attached form PTO-1449 is submitted in compliance with 37 C.F.R. §1.56. Copies of the cited art are included. No admission is made regarding whether all the submitted references are prior art.

This Supplemental Information Disclosure Statement is being filed before the mailing of a first Office Action following the filing of a Request for Continued Examination. Therefore, no fee is believed to be required per 37 C.F.R. § 1.97(b)(4). However, in the event that a fee is required for filing this Supplemental Information Disclosure Statement, please charge the fee specified under 37 C.F.R. § 1.17(p) to Deposit Account No. 23-0925.

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Respectfully submitted,

Dated:

10-1-02

Attorney:

Mark S. Matkin
Reg. No. 32,268

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